

Cascadable Silicon Bipolar MMIC Amplifier

Technical Data

MSA-0486

Features

- **Cascadable 50 Ω Gain Block**
- **3 dB Bandwidth:**
DC to 3.2 GHz
- **8 dB Typical Gain at 1.0 GHz**
- **12.5 dBm Typical P_{1 dB} at 1.0 GHz**
- **Unconditionally Stable (k > 1)**
- **Surface Mount Plastic Package**
- **Tape-and-Reel Packaging Option Available^[1]**

Note:

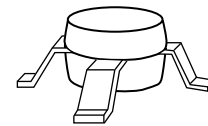
1. Refer to PACKAGING section "Tape-and-Reel Packaging for Surface Mount Semiconductors".

Description

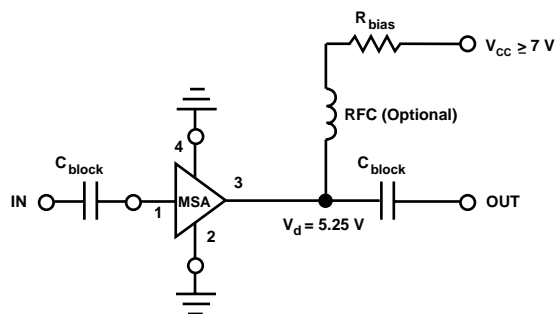
The MSA-0486 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50 Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using HP's 10 GHz f_T , 25 GHz f_{MAX} , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

86 Plastic Package



Typical Biasing Configuration



MSA-0486 Absolute Maximum Ratings

| Parameter | Absolute Maximum ^[1] |
|------------------------------------|---------------------------------|
| Device Current | 85 mA |
| Power Dissipation ^[2,3] | 500 mW |
| RF Input Power | +13 dBm |
| Junction Temperature | 150°C |
| Storage Temperature | -65 to 150°C |

Thermal Resistance^[2,4]:

$$\theta_{jc} = 100^{\circ}\text{C}/\text{W}$$

Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2. $T_{\text{CASE}} = 25^{\circ}\text{C}$.
3. Derate at 10 mW/°C for $T_{\text{C}} > 100^{\circ}\text{C}$.
4. See MEASUREMENTS section "Thermal Resistance" for more information.

Electrical Specifications^[1], $T_{\text{A}} = 25^{\circ}\text{C}$

| Symbol | Parameters and Test Conditions: $I_{\text{d}} = 50 \text{ mA}$, $Z_0 = 50 \Omega$ | Units | Min. | Typ. | Max. |
|-----------------------|--|-------|------|------------|------|
| G_{P} | Power Gain ($ S_{21} ^2$) f = 0.1 GHz f = 1.0 GHz | dB | 7.0 | 8.3 8.0 | |
| ΔG_{P} | Gain Flatness f = 0.1 to 2.0 GHz | dB | | ± 0.6 | |
| f_3 dB | 3 dB Bandwidth | GHz | | 3.2 | |
| VSWR | Input VSWR f = 0.1 to 3.0 GHz | | | 1.5:1 | |
| | Output VSWR f = 0.1 to 3.0 GHz | | | 1.9:1 | |
| NF | 50 Ω Noise Figure f = 1.0 GHz | dB | | 7.0 | |
| $P_{1 \text{ dB}}$ | Output Power at 1 dB Gain Compression f = 1.0 GHz | dBm | | 12.5 | |
| IP_3 | Third Order Intercept Point f = 1.0 GHz | dBm | | 25.5 | |
| t_{D} | Group Delay f = 1.0 GHz | psec | | 140 | |
| V_{d} | Device Voltage | V | 4.2 | 5.25 | 6.3 |
| dV/dT | Device Voltage Temperature Coefficient | mV/°C | | -8.0 | |

Note:

1. The recommended operating current range for this device is 30 to 70 mA. Typical performance as a function of current is on the following page.

Part Number Ordering Information

| Part Number | No. of Devices | Container |
|--------------|----------------|----------------|
| MSA-0486-TR1 | 1000 | 7" Reel |
| MSA-0486-BLK | 100 | Antistatic Bag |

For more information, see "Tape and Reel Packaging for Semiconductor Devices".

MSA-0486 Typical Scattering Parameters ($Z_0 = 50 \Omega$, $T_A = 25^\circ\text{C}$, $I_d = 50 \text{ mA}$)

| Freq. GHz | S_{11} | | S_{21} | | | S_{12} | | | S_{22} | |
|--------------|----------|-----|----------|------|-----|----------|------|-----|----------|------|
| | Mag | Ang | dB | Mag | Ang | dB | Mag | Ang | Mag | Ang |
| 0.1 | .14 | 178 | 8.4 | 2.62 | 175 | -16.2 | .154 | 1 | .16 | -10 |
| 0.2 | .14 | 175 | 8.3 | 2.61 | 170 | -16.3 | .153 | 2 | .16 | -20 |
| 0.4 | .14 | 171 | 8.2 | 2.57 | 161 | -16.3 | .154 | 3 | .17 | -39 |
| 0.6 | .13 | 168 | 8.1 | 2.54 | 151 | -16.0 | .158 | 4 | .18 | -57 |
| 0.8 | .13 | 166 | 8.0 | 2.52 | 141 | -15.9 | .161 | 5 | .20 | -74 |
| 1.0 | .13 | 165 | 7.9 | 2.48 | 131 | -15.7 | .165 | 6 | .21 | -88 |
| 1.5 | .15 | 168 | 7.7 | 2.42 | 108 | -14.8 | .182 | 8 | .27 | -121 |
| 2.0 | .21 | 168 | 7.3 | 2.32 | 84 | -14.0 | .199 | 7 | .32 | -149 |
| 2.5 | .29 | 165 | 6.8 | 2.18 | 65 | -13.1 | .222 | 4 | .38 | -168 |
| 3.0 | .37 | 153 | 5.9 | 1.97 | 43 | -12.7 | .231 | -1 | .40 | 173 |
| 3.5 | .44 | 142 | 4.8 | 1.74 | 24 | -12.5 | .238 | -5 | .41 | 157 |
| 4.0 | .50 | 130 | 3.6 | 1.52 | 7 | -12.5 | .238 | -10 | .41 | 145 |
| 5.0 | .61 | 109 | 1.3 | 1.16 | -21 | -12.7 | .231 | -17 | .43 | 132 |

A model for this device is available in the DEVICE MODELS section.

Typical Performance, $T_A = 25^\circ\text{C}$

(unless otherwise noted)

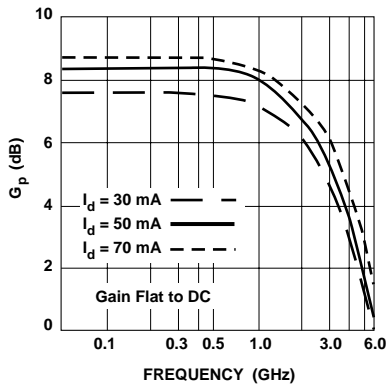


Figure 1. Typical Power Gain vs. Frequency, $T_A = 25^\circ\text{C}$.

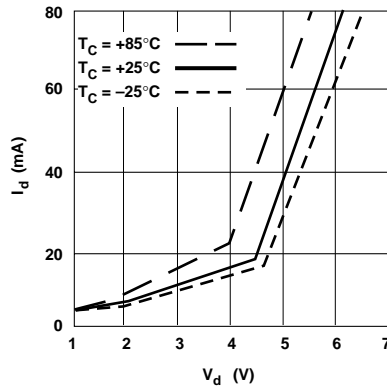


Figure 2. Device Current vs. Voltage.

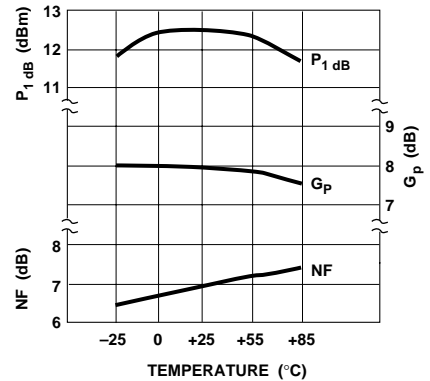


Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, $f = 1.0 \text{ GHz}$, $I_d = 50 \text{ mA}$.

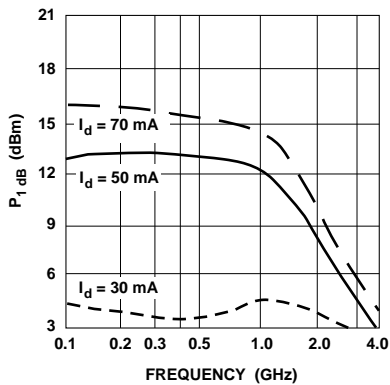


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

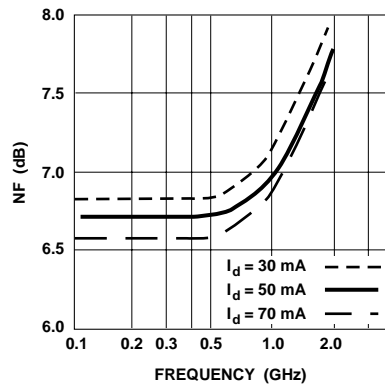
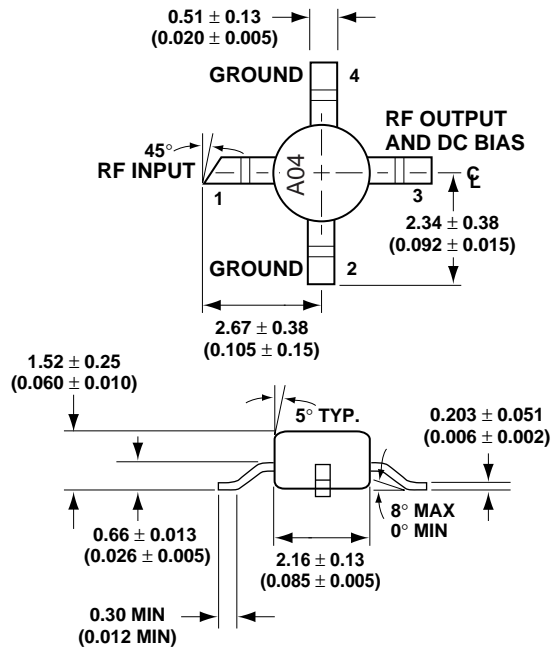


Figure 5. Noise Figure vs. Frequency.

86 Plastic Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES)